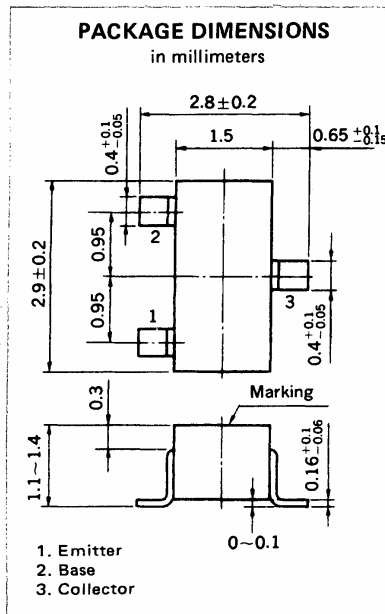


HIGH VOLTAGE AMPLIFIER AND SWITCHING
NPN SILICON EPITAXIAL TRANSISTOR
MINI MOLD



FEATURES

- High Voltage $V_{CE0} = 200$ V
- High DC Current Gain $h_{FE} = 90$ to 450
- Complementary to 2SA1330

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C)

Collector to Base Voltage	V_{CBO}	200	V
Collector to Emitter Voltage	V_{CEO}	200	V
Emitter to Base Voltage	V_{EBO}	5	V
Collector Current (DC)	I_C	100	mA
Total Power Dissipation	P_T	200	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 to +150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	I_{CBO}			100	nA	$V_{CB} = 200$ V, $I_E = 0$
Emitter Cutoff Current	I_{EBO}			100	nA	$V_{EB} = 5.0$ V, $I_C = 0$
DC Current Gain	h_{FE1}^*	90	200	450		$V_{CE} = 10$ V, $I_C = 10$ mA
DC Current Gain	h_{FE2}^*	50	200			$V_{CE} = 10$ V, $I_C = 50$ mA
Base to Emitter Voltage	V_{BE}^*	0.6	0.64	0.7	V	$V_{CE} = 10$ V, $I_C = 10$ mA
Collector Saturation Voltage	$V_{CE(sat)}^*$		0.1	0.3	V	$I_C = 50$ mA, $I_B = 5$ mA
Base Saturation Voltage	$V_{BE(sat)}^*$		0.8	1.2	V	$I_C = 50$ mA, $I_B = 5$ mA
Output Capacitance	C_{ob}		2.8		pF	$V_{CB} = 30$ V, $I_E = 0$, $f = 1.0$ MHz
Gain Bandwidth Product	f_T		160		MHz	$V_{CE} = 10$ V, $I_E = -10$ mA
Turn-on Time	t_{on}		0.15		μs	$I_C = 10$ mA, $I_{B1} = -I_{B2} = 1$ mA
Turn-off Time	t_{off}		1.6		μs	$V_{CC} = 10$ V

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* Pulsed: $PW \leq 350$ μs, Duty Cycle ≤ 2 %

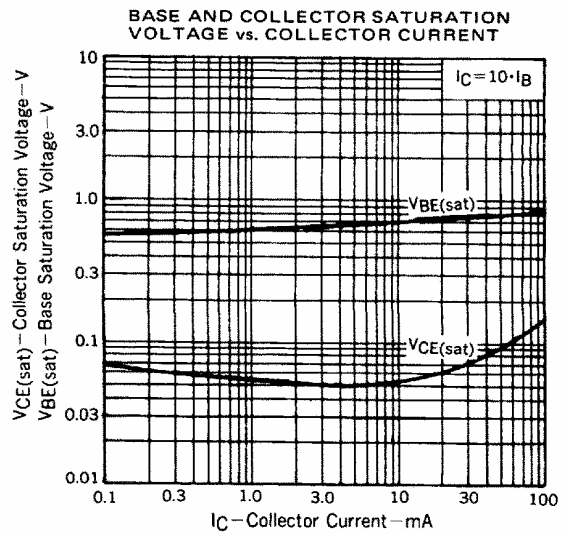
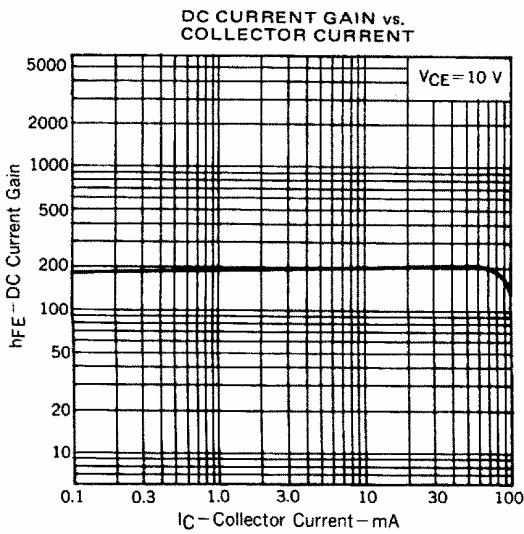
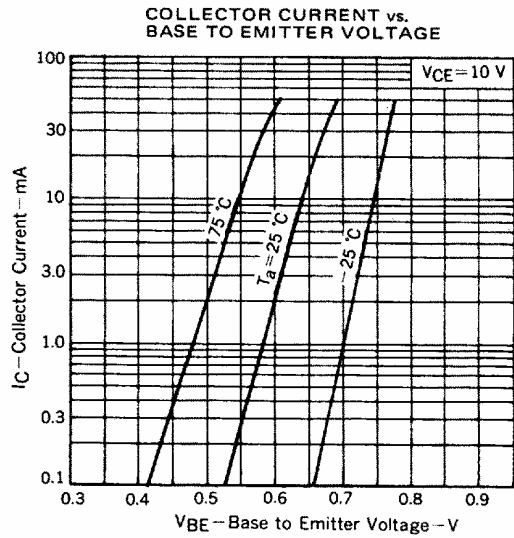
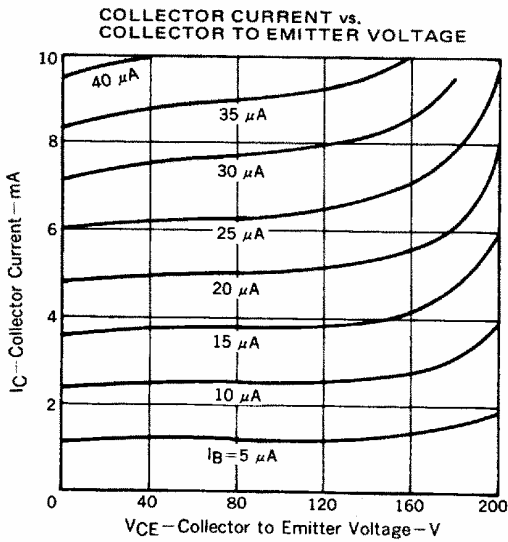
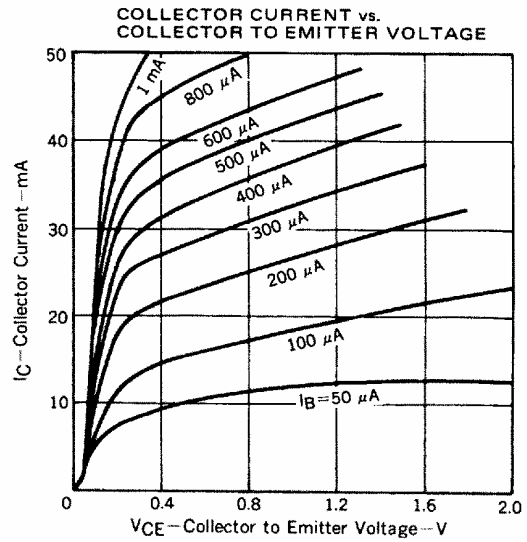
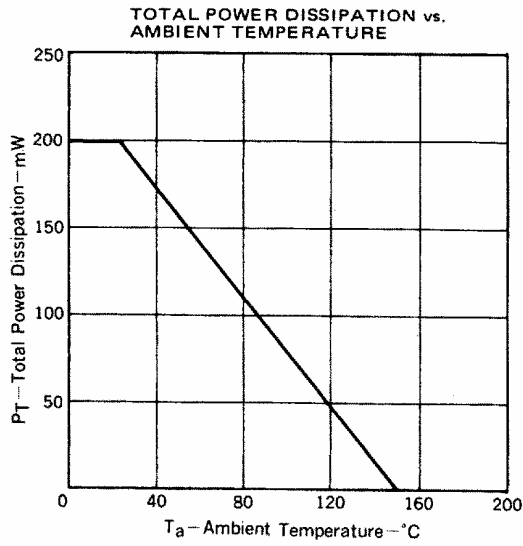
h_{FE} Classification

Marking	N15	N16	N17
h_{FE1}	90 to 180	135 to 270	200 to 450

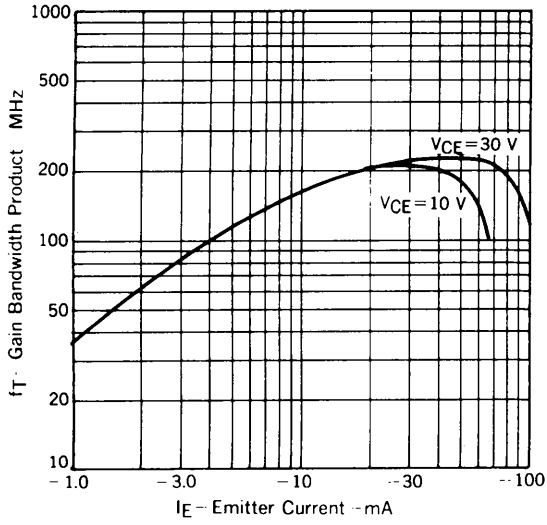
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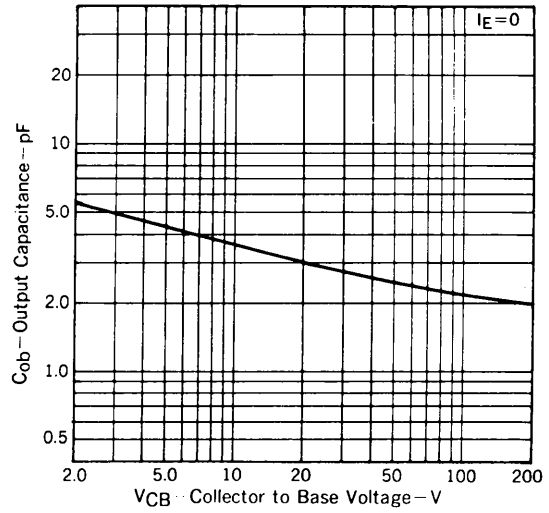
TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)



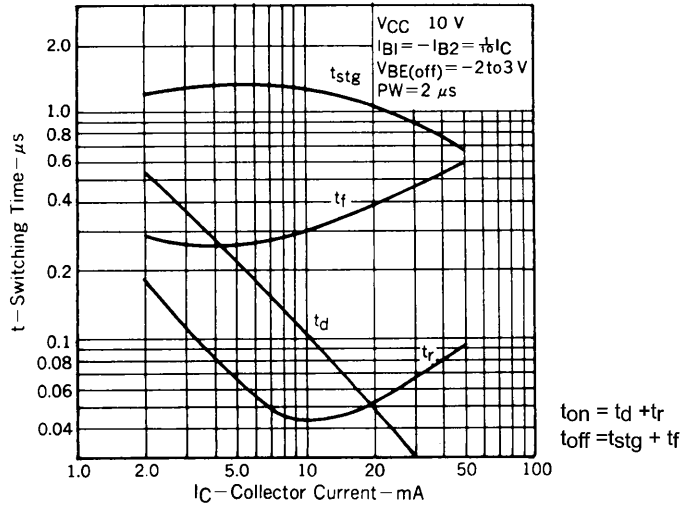
GAIN BANDWIDTH PRODUCT vs. EMITTER CURRENT



OUTPUT CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



SWITCHING TIME vs. COLLECTOR CURRENT



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